## NSN 5962-01-015-8538

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View Online at https://aerobasegroup.com/nsn/5962-01-015-8538 **Body Length:** Between 0.660 inches and 0.785 inches **Body Width:** Between 0.220 inches and 0.280 inches **Body Height:** Between 0.140 inches and 0.180 inches **Maximum Power Dissipation Rating:** 450.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and programmable and programmed and w/storage **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Current-mode logic **Input Circuit Pattern:** 8 input **Case Outline Source And Designator:** T0-116 joint electron device engineering council **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 50.0 volts power source **Time Rating Per Chacteristic:** 50.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Diode matrix **Test Data Document:** 30003-420as116 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 14 printed circuit Shelf Life: N/a

Demilitarization:

**Unit Of Measure:** 

Yes - demil/mli

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